



## Ultrahigh-Speed Switching Applications

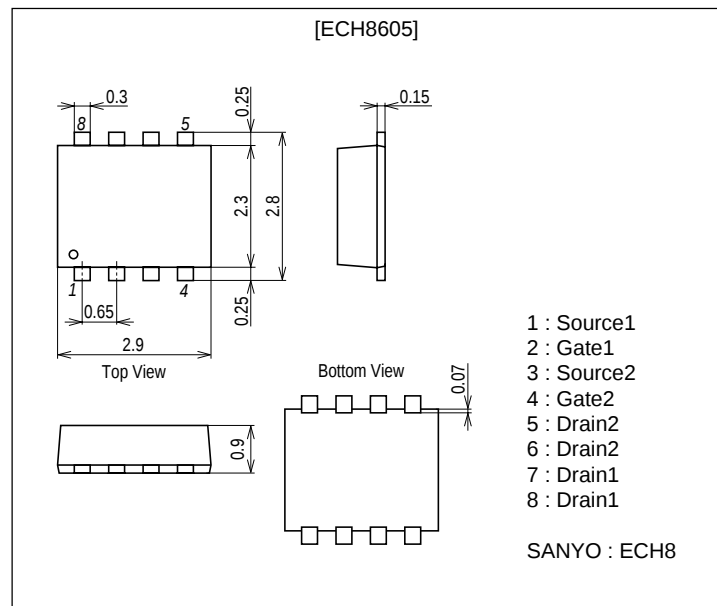
### Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 4V drive.

### Package Dimensions

unit : mm

2206A



### Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter                   | Symbol    | Conditions                                             | Ratings     | Unit |
|-----------------------------|-----------|--------------------------------------------------------|-------------|------|
| Drain-to-Source Voltage     | $V_{DS}$  |                                                        | -30         | V    |
| Gate-to-Source Voltage      | $V_{GS}$  |                                                        | ±20         | V    |
| Drain Current (DC)          | $I_D$     |                                                        | -4          | A    |
| Drain Current (Pulse)       | $I_{DP}$  | $PW \leq 10\mu s$ , duty cycle $\leq 1\%$              | -40         | A    |
| Allowable Power Dissipation | $P_D$     | Mounted on a ceramic board (900mm $\times$ 0.8mm)1unit | 1.3         | W    |
| Total Dissipation           | $P_T$     | Mounted on a ceramic board (900mm $\times$ 0.8mm)      | 1.5         | W    |
| Channel Temperature         | $T_{ch}$  |                                                        | 150         | °C   |
| Storage Temperature         | $T_{stg}$ |                                                        | -55 to +150 | °C   |

### Electrical Characteristics at Ta=25°C

| Parameter                         | Symbol        | Conditions                        | Ratings |     |      | Unit    |
|-----------------------------------|---------------|-----------------------------------|---------|-----|------|---------|
|                                   |               |                                   | min     | typ | max  |         |
| Drain-to-Source Breakdown Voltage | $V_{(BR)DS}$  | $I_D = -1mA$ , $V_{GS} = 0$       | -30     |     |      | V       |
| Zero-Gate Voltage Drain Current   | $I_{DSS}$     | $V_{DS} = -30V$ , $V_{GS} = 0$    |         |     | -1   | $\mu A$ |
| Gate-to-Source Leakage Current    | $I_{GSS}$     | $V_{GS} = \pm 16V$ , $V_{DS} = 0$ |         |     | ±10  | $\mu A$ |
| Cutoff Voltage                    | $V_{GS(off)}$ | $V_{DS} = -10V$ , $I_D = -1mA$    | -1.0    |     | -2.4 | V       |

Marking : JD

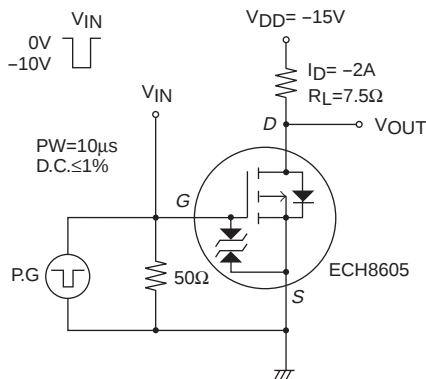
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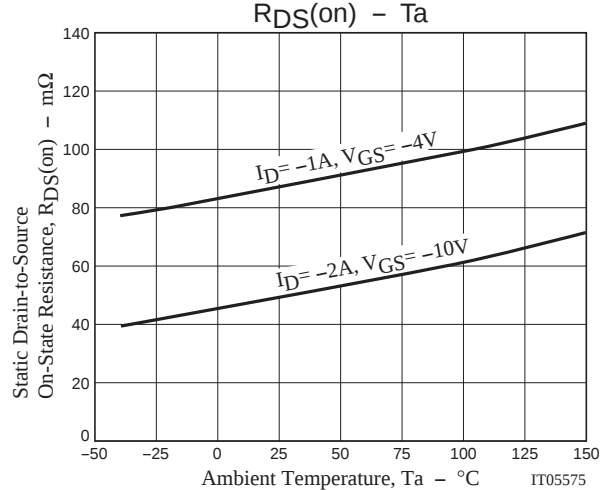
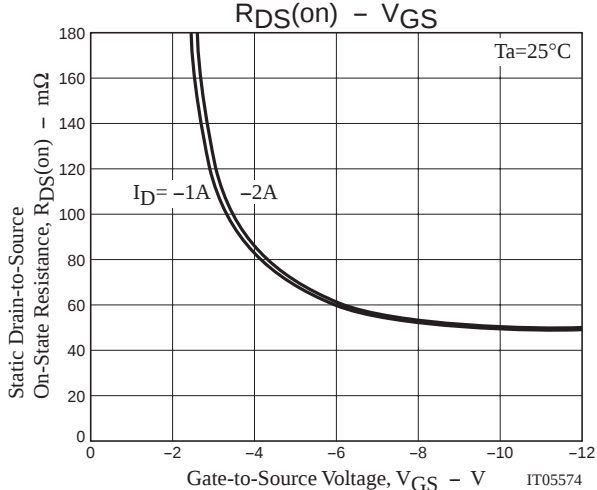
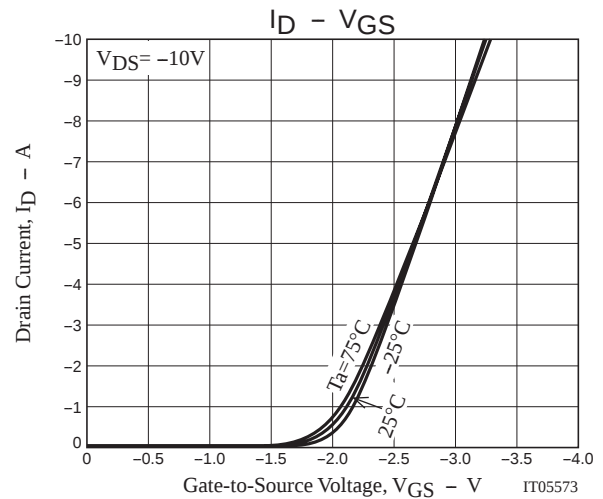
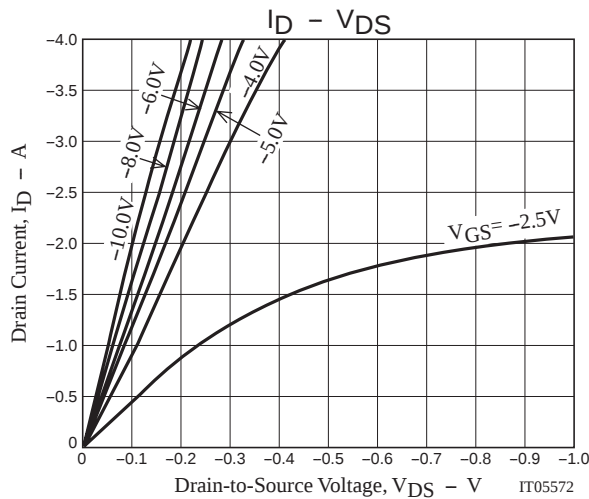
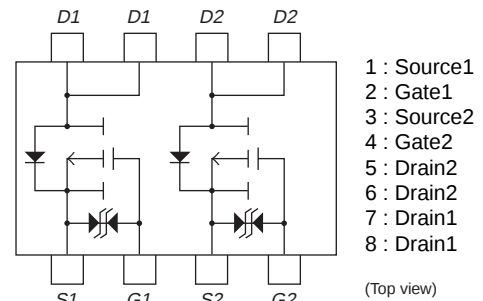
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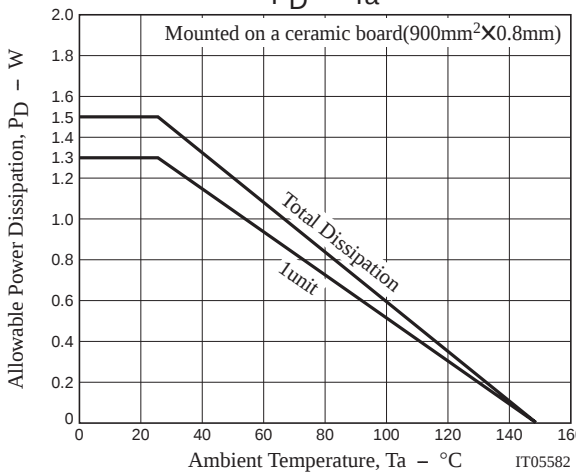
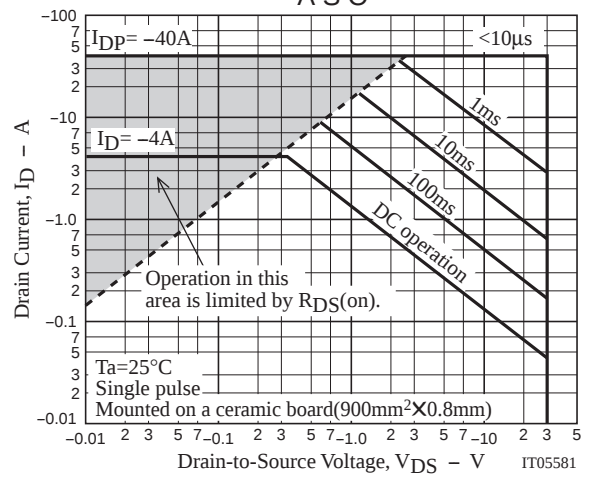
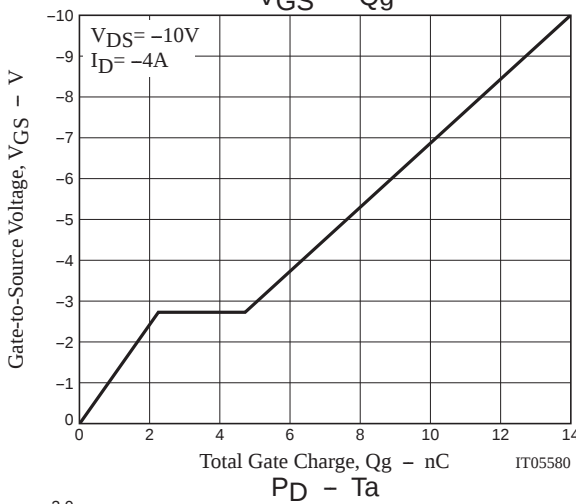
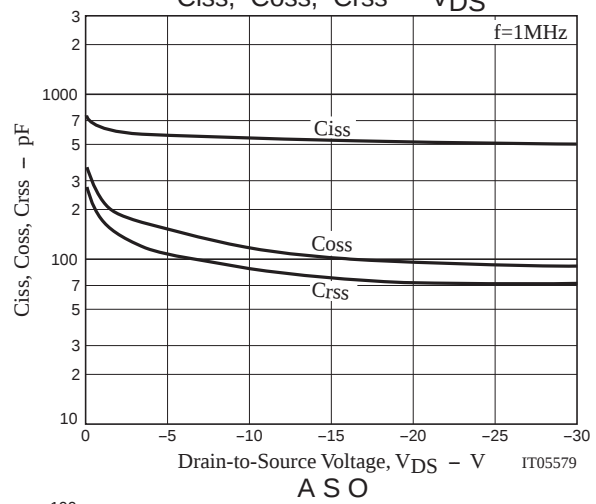
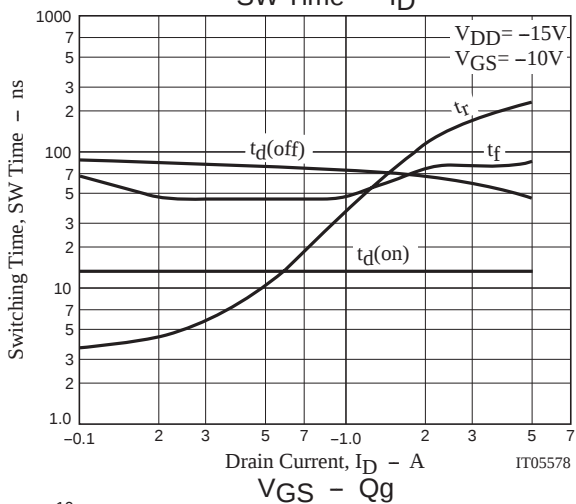
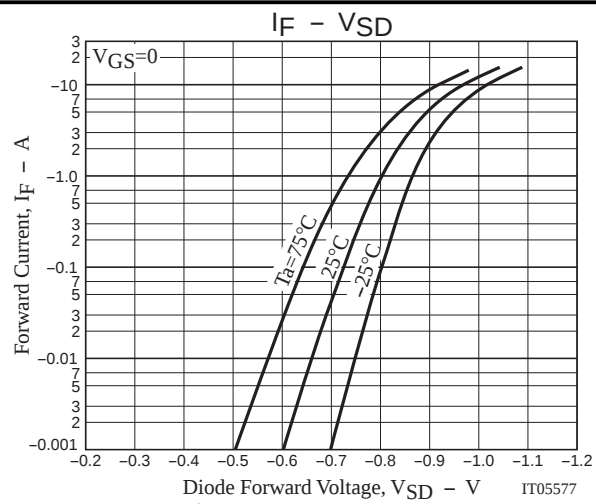
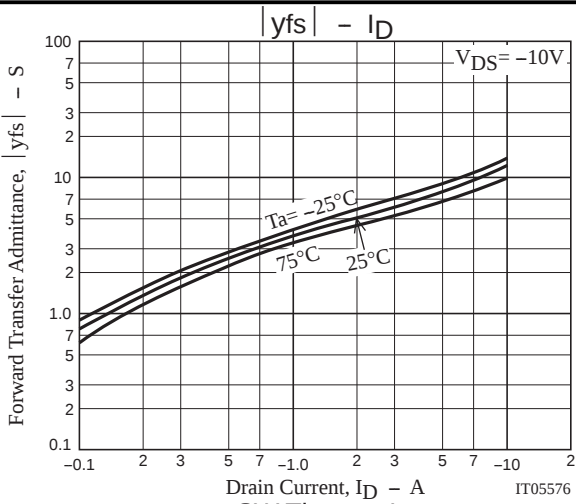
| Parameter                                  | Symbol        | Conditions                          | Ratings |       |      | Unit      |
|--------------------------------------------|---------------|-------------------------------------|---------|-------|------|-----------|
|                                            |               |                                     | min     | typ   | max  |           |
| Forward Transfer Admittance                | $ y_{fs} $    | $V_{DS}=-10V, I_D=-2A$              | 3.3     | 5     |      | S         |
| Static Drain-to-Source On-State Resistance | $R_{DS(on)1}$ | $I_D=-2A, V_{GS}=-10V$              |         | 50    | 67   | $m\Omega$ |
|                                            | $R_{DS(on)2}$ | $I_D=-1A, V_{GS}=-4V$               |         | 87    | 120  | $m\Omega$ |
| Input Capacitance                          | $C_{iss}$     | $V_{DS}=-10V, f=1MHz$               |         | 550   |      | pF        |
| Output Capacitance                         | $C_{oss}$     | $V_{DS}=-10V, f=1MHz$               |         | 120   |      | pF        |
| Reverse Transfer Capacitance               | $C_{rss}$     | $V_{DS}=-10V, f=1MHz$               |         | 90    |      | pF        |
| Turn-ON Delay Time                         | $t_d(on)$     | See specified Test Circuit.         |         | 13    |      | ns        |
| Rise Time                                  | $t_r$         | See specified Test Circuit.         |         | 110   |      | ns        |
| Turn-OFF Delay Time                        | $t_d(off)$    | See specified Test Circuit.         |         | 65    |      | ns        |
| Fall Time                                  | $t_f$         | See specified Test Circuit.         |         | 75    |      | ns        |
| Total Gate Charge                          | $Q_g$         | $V_{DS}=-10V, V_{GS}=-10V, I_D=-4A$ |         | 14    |      | nC        |
| Gate-to-Source Charge                      | $Q_{gs}$      | $V_{DS}=-10V, V_{GS}=-10V, I_D=-4A$ |         | 2.2   |      | nC        |
| Gate-to-Drain "Miller" Charge              | $Q_{gd}$      | $V_{DS}=-10V, V_{GS}=-10V, I_D=-4A$ |         | 2.5   |      | nC        |
| Diode Forward Voltage                      | $V_{SD}$      | $I_S=-4A, V_{GS}=0$                 |         | -0.88 | -1.2 | V         |

## Switching Time Test Circuit



## Electrical Connection





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